## NSN 5961-00-232-7322

No Fiig: A110a0

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View Online at https://aerobasegroup.com/nsn/5961-00-232-7322 **Inclosure Material:** Plastic **Overall Length:** 0.785 inches **Terminal Length:** 0.155 inches **Overall Height:** 0.180 inches **Overall Width:** 0.250 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-116 **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage, dc all transistor and 40.0 collector to emitter voltage, dc all transistor and 5.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 1.5 watts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 14 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**